

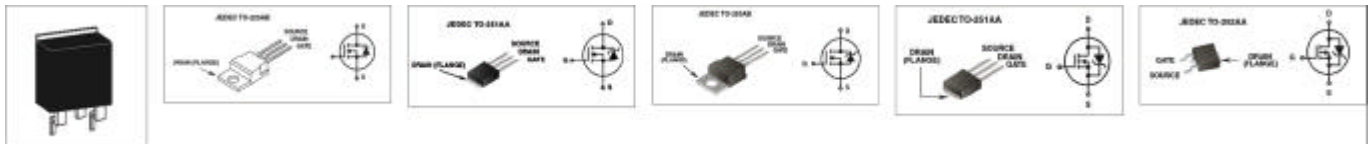
# SEMICONDUCTORS-DISCRETES

PartNo.	ProductNo.	Manuf.	Description	N/P	Vdss(max.)	Rds(on)(max)	Pd(max)	Id(max)	Pins/Package
6094	IRFP264	IR	HEXFETpowerMOSFET	N-Ch	250V	0.075	280W	38A	3P/TO-247AC
14440	IRFP350	Intersil	N-Channel PowerMOSFET	N-Ch.	400V	0.3	190W	16A	3P/TO-247AC
17948	IRFP360	IR	POWERMOSFET	N	400V	0.2	300W	23A	3P/TO-247AD
6095	IRFP450	IR	N-Channel Power MOSFET	N-Ch	500V	0.4	180W	14A	3P/TO-247AC
16193	IRFP460	ST(SGS)	N-CHANNEL	N-Ch.	500V	0.22	220W	18.4A	3P/TO-247
18440	IRFR210	IR	PowerMOSFET	N-Ch.	200V	1.5	25W	2.6A	2P/TO-252AA
16425	IRFR220B	Fairchild	Enhancement mode field effect transistor	N-Ch.	200V	0.80	42W	4.6A	2P/TO-252AA
19649	IRFR224	IR	SMD PowerMOSFET	N-Ch.	250V	1.1	42W	3.8A	TO-252AA
19641	IRFR310	IR	SMD PowerMOSFET	N-Ch.	400V	3.6	25W	1.7A	TO-252AA(D-PAK)
14212	IRFR320	IR	Power MOSFET	N-Ch.	400V	1.8	50W	3.1A	2P/TO-252AA
19644	IRFR3910	IR	SMD Power MOSFET	N-Ch.	100V	0.115	79W	16A	TO-252AA(D-PAK)
8234	IRFR420	HARRIS	PowerMOSFET	N-Ch	500V	3.0	50W	2.5A	2P/TO-252A(DPAK)
19645	IRFR9014	IR	SMD PowerMOSFET	P-Ch.	-60V	0.5	25W	-5.1A	TO-252AA(D-PAK)
18445	IRFR9020	IR	PowerMOSFET	P	-50V			-9.9A	3P/TO-252AA
18442	IRFR9024	IR	PowerMOSFET	P-Ch.	-60V	0.28	42W	-8.8A	3P/TO-252AA
19646	IRFR9120	IR	SMD PowerMOSFET	P-Ch.	-100V	0.6	42W	-5.6A	TO-252AA(D-PAK)
18443	IRFR9210	IR	PowerMOSFET	P	-200V	3	25W	-1.9A	3P/TO-252AA
18444	IRFR9310	IR	Power MOSFET	P	-400V	7	50W	-1.8A	3P/TO-252AA
14896	IRFS634B	Fairchild	N-channel MOSFET	N-Ch.	250V	0.45	38W	8.1A	3P/TO-220F
16102	IRFU220	IR	Power MOSFET	N-Ch.	200V	0.8	50W	4.6A	2P/TO-251AA
6098	IRFZ20	HARRIS	MOSFET	N-Ch	50V	0.1	40W	15A	3P/TO-220AB
16483	IRFZ4N	IR	Enhancement mode TrenchMOS(tm) transistor	N-Ch.	55V	0.07	45W	17A	3P/TO-220
19642	IRFZ24NS	IR	SMD PowerMOSFET	N-Ch.	55V	0.07	45W	17A	TO-263
6103	IRFZ30	HARRIS	PowerN-ChannelMOSFETs	N-Ch	50V	0.1	40W	15A	3P/TO-220AB
15669	IRFZ34N	MOT.	Power MOSFET	N-Ch.	55V	0.04	56W	26A	3P/TO-220
8235	IRFZ44N	IR	N-channel enhancement mode TrenchMOS(tm) transistor	N-Ch.	55V	0.024	83W	41A	3P/TO-220
19632	IRFZ44NS	IR	Surface Mount PowerMOSFET	N-Ch.	100V	0.077	150W	28A	TO-263(D2Pak)
17947	IRFZ48N	IR	ENHANCEMENT MODE TRENCHMOSO, TRANSISTOR	N-Ch.	55V	0.016	130W	62A	3P/TO-220AB
18441	IRLR3103	IR	PowerMOSFET	N	30V	0.019	107W	60A	3P/TO-252AA
18751	RF1S630SM	IR	PowerMOSFET	N	200V	0.4	75W	9A	TO-263

## 其它系列功率场效電晶體

## Other Series Power MOSFET

詳細產品規格--請點擊[www.100y.com.tw](http://www.100y.com.tw)



PartNo.	ProductNo.	Manuf.	Description	N/P	Vdss(max.)	Rds(on)(max)	Pd(max)	Id(max)	Pins/Package
16294	APT5020BVF	APT	N-Ch. Enhancement powerMOSFET	N	500V	0.2	300W	26A	3P/TO-247
22498	BS107		TO-92 Small Signal MOSFET		200V	14	350mW	250-500mA	3P/TO-92
22499	BS107T	PHILIPS	N-channel enhancement mode vertical D-MOS transistor	N	200V	28	830mW	150mA	3P/TO-92
3926	BUZ11	SIEMENS	N-Channel Power MOSFET	N	50V	0.04	120W	36A	3P/TO-220
21342	CEB6060L	CET	N-Channel Enhancement Mode Field Effect Transistor	N	60V	10Vgs/20m 5Vgs/25m	100W	48A	3P/TO-263(DD-PAK)
26475	CEM9435A	CET	Dual N-channel enhancement mode field effect transistor	P	-30V 10Vgs/50m 4.5Vds/90m		2W	±3A	8P/SOIC
14402	CEM9945	CET	Dual N-channel enhancement mode field effect transistor	N	60V 10Vgs/0.1 4.5Vds/0.2		2W	±3A	8P/SOIC
19648	FDD6030L	Fairchild	SMD PowerMOSFET	N-Ch.	30V	14.5m	56W	12A	TO-252AA(D-PAK)
18053	FS14SM-12	MITSUBISHI	Power mosfet for high-speed switching use	N	600V	0.85	275W	14A	3P/TO-3P
14116	HU603AL	HSMC	Logic Level Enhancement Mode Field Effect Transistor	N	30V	0.022	60W	30A	2P/TO-263
16281	IXFK48N50C	IXYS	N-Ch. Enhancement Mode	N	500V	0.1	500W	48A	3P/TO-264AA
13256	MMBF0201NLT	ON-Semi.	PowerMOSFET	N	20V	1	225mW	300mA	3P/SOT-23
13233	MMFT3055VLT1	ON-Semi.	PowerMOSFET	N	60V	140m	2.1W	1A	4P/SOT-223
13230	MTD2955V	ON-Semi.	PowerMOSFET	P	60V	230m	60W	12A	TO-252(D-PAK)
13231	MTD3055VLT4	ON-Semi.	N-Ch. Enhancement Mode Field Effect Transistor	N	60V	150m	48W	12A	DPAK
11875	MTP16N05	MOT.	MOSFET	N	50V	120m	55W	16A	3P/TO-220AB
17498	P3055LS	niko-sem	Power Mosfet	N	20V	50m	43W/25 15W/10	12A	2P/TO-263
13885	RFD10P03LSM	Fairchild	P-Ch. PowerMOSFET	P	30V	0.2	60W	10A	2P/TO-252
17589	RFD14N05	Fairchild	Logic Level Power MOSFET	N-Ch.		0.1	50V	14A	TO-252AA
14579	RFD14N05	Fairchild	PowerMOSFET	N-Ch		0.1	50V	14A	3P/TO-251AA
3933	RFD15P05	Intersil	P-Ch. PowerMOSFET	P	50V	0.15	67.5W	15A	TO-251(I-Pak)
12987	RFD15P05SM	HARRIS	P-Channel PowerMOSFET	P	50V	0.15	80W	15A	2P/TO-252(16)
3931	RFD16N05	Fairchild	Logic Level, N-Ch. PowerMOSFETs	N	50V	0.047	60W	16A	3P/TO-251(I-Pak)
3938	RFP50N06	HARRIS	N-Ch. Power MOSFET	N	60V	0.022	131W	50A	3P/TO-220
3939	RFP70N06	HARRIS	N-Channel PowerMOSFET	N	60V	0.014	150W	70A	3P/TO-220

